Diode Semiconductor Device - Page 1 of 1



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In	closure Material:
Gl	lass and metal
0	verall Length:
0.	531 inches
0	verall Diameter:
0.	500 inches
M	ounting Facility Quantity:
1	
M	ounting Method:
Tł	nreaded stud
Fe	eatures Provided:
He	ermetically sealed case
Tł	nread Size:
0.	138 inches
Se	emiconductor Material:
Si	licon
Vo	oltage Rating In Volts Per Characteristic:
40	00.0 reverse voltage, peak
С	urrent Rating Per Characteristic:
5.	00 amperes forward current, average absolute
M	aximum Operating Tempurature Per Measurement Point:
17	70.0 degrees celsius case
Tł	nread Series Designator:
Ur	nc
Te	erminal Type And Quantity:
1 1	threaded stud and 1 ferrule
Sł	nelf Life:
N/	'a
Uı	nit Of Measure:
De	emilitarization:
No	0
Fi	ig:
A1	110a0